THE DATASHEET OF

CSD19538Q3AT

CSD19538Q3A 100-V N-Channel NexFET™ Power MOSFET

1 Features

- Ultra-Low Q_g and Q_{gd}
- Low-Thermal Resistance
- Avalanche Rated
- Lead Free
- RoHS Compliant
- Halogen Free
- SON 3.3-mm × 3.3-mm Plastic Package

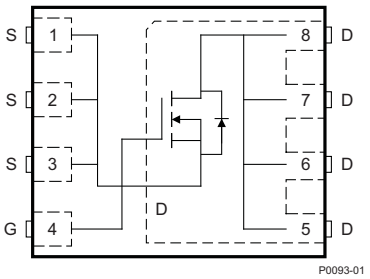
2 Applications

- Power Over Ethernet (PoE)
- Power Sourcing Equipment (PSE)
- Motor Control

3 Description

This 100-V, 49-mΩ, SON 3.3-mm × 3.3-mm NexFET™ power MOSFET is designed to minimize conduction losses and reduce board footprint in PoE applications.

Top View



Product Summary

T_A = 25°C		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	100		V
Q_g	Gate Charge Total (10 V)	4.3		nC
Q_{gd}	Gate Charge Gate to Drain	0.8		nC
$R_{DS(on)}$	Drain-to-Source On Resistance	V_{GS} = 6 V	58	mΩ
		V_{GS} = 10 V	49	
$V_{GS(th)}$	Threshold Voltage	3.2		V

Device Information(1)

DEVICE	MEDIA	QTY	PACKAGE	SHIP
CSD19538Q3A	13-Inch Reel	3000	SON 3.30-mm × 3.30-mm Plastic Package	Tape and Reel
CSD19538Q3AT	7-Inch Reel	250		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

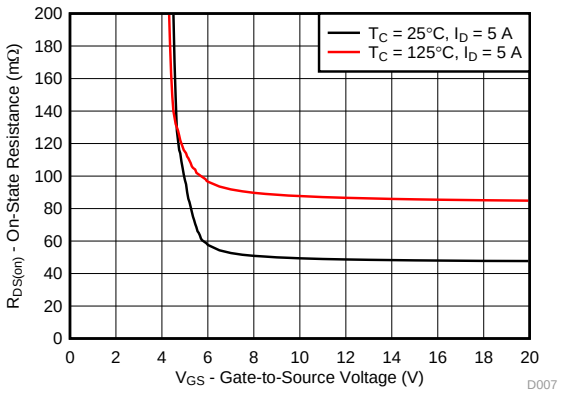
Absolute Maximum Ratings

T_A = 25°C		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	100	V
V_{GS}	Gate-to-Source Voltage	±20	V
I_D	Continuous Drain Current (Package Limited)	15	A
	Continuous Drain Current (Silicon Limited), T_C = 25°C	14	
	Continuous Drain Current(1)	4.9	
I_{DM}	Pulsed Drain Current(2)	37	A
P_D	Power Dissipation(1)	2.8	W
	Power Dissipation, T_C = 25°C	23	
T_J, T_{stg}	Operating Junction Temperature, Storage Temperature	–55 to 150	°C
E_{AS}	Avalanche Energy, Single Pulse I_D = 12.7 A, L = 0.1 mH, R_G = 25 Ω	8.1	mJ

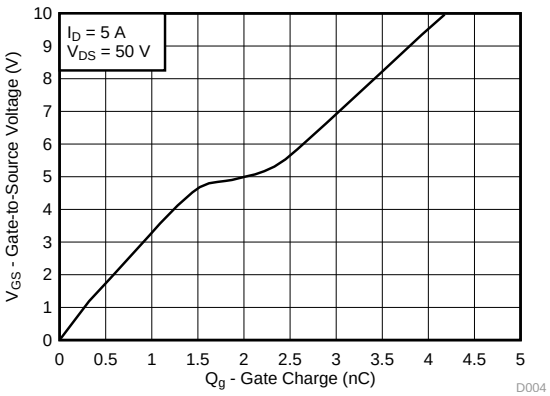
(1) Typical $R_{\theta JA}$ = 45°C/W on a 1-in^2, 2-oz Cu pad on a 0.06 in thick FR4 PCB.

(2) Max $R_{\theta JC}$ = 5.5°C/W, pulse duration ≤ 100 µs, duty cycle ≤ 1%.

$R_{DS(on)}$ vs V_{GS}



Gate Charge



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4 Revision History

Changes from Original (May 2016) to Revision A **Page**

- Changed the test voltage V_{DS} in Gate Charge curve from 100 V : to 50 V ... 1
- Changed the test voltage V_{DS} in Figure 4 from 100 V : to 50 V ... 5
- Added *Receiving Notification of Documentation Updates* section to *Device and Documentation Support* section ... 7

5 Specifications

5.1 Electrical Characteristics

T_A = 25°C

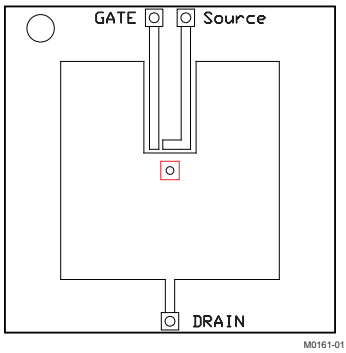
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV_{DSS}	Drain-to-source voltage	V_{GS} = 0 V, I_D = 250 μA	100			V
I_{DSS}	Drain-to-source leakage current	V_{GS} = 0 V, V_{DS} = 80 V			1	μA
I_{GSS}	Gate-to-source leakage current	V_{DS} = 0 V, V_{GS} = 20 V			100	nA
$V_{GS(th)}$	Gate-to-source threshold voltage	V_{DS} = V_{GS}, I_D = 250 μA	2.8	3.2	3.8	V
$R_{DS(on)}$	Drain-to-source on resistance	V_{GS} = 6 V, I_D = 5 A		58	72	mΩ
		V_{GS} = 10 V, I_D = 5 A		49	59	
g_{fs}	Transconductance	V_{DS} = 10 V, I_D = 5 A		6.1		S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input capacitance	V_{GS} = 0 V, V_{DS} = 50 V, f = 1 MHz		349	454	pF
C_{oss}	Output capacitance			69	90	pF
C_{rss}	Reverse transfer capacitance			12.6	16.4	pF
R_G	Series gate resistance			4.6	9.2	Ω
Q_g	Gate charge total (10 V)	V_{DS} = 50 V, I_D = 5 A		4.3		nC
Q_{gd}	Gate charge gate-to-drain			0.8		nC
Q_{gs}	Gate charge gate-to-source			1.6		nC
$Q_{g(th)}$	Gate charge at V_{th}			1		nC
Q_{oss}	Output charge	V_{DS} = 50 V, V_{GS} = 0 V		12.3		nC
$t_{d(on)}$	Turnon delay time	V_{DS} = 50 V, V_{GS} = 10 V, I_{DS} = 5 A, R_G = 0 Ω		5		ns
t_r	Rise time			3		ns
$t_{d(off)}$	Turnoff delay time			7		ns
t_f	Fall time			2		ns
DIODE CHARACTERISTICS						
V_{SD}	Diode forward voltage	I_{SD} = 5 A, V_{GS} = 0 V		0.85	1	V
Q_{rr}	Reverse recovery charge	V_{DS}= 50 V, I_F = 5 A, di/dt = 300 A/μs		94		nC
t_{rr}	Reverse recovery time			32		ns

5.2 Thermal Information

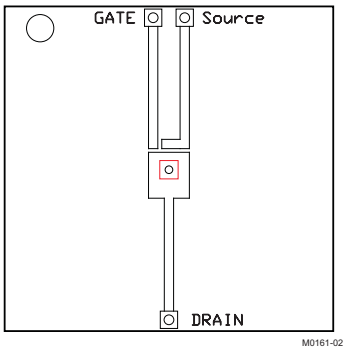
T_A = 25°C (unless otherwise stated)

THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance (1)			5.5	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance (1) (2)			55	°C/W

(1) $R_{\theta JC}$ is determined with the device mounted on a 1-in^2 (6.45-cm^2), 2-oz (0.071-mm) thick Cu pad on a 1.5-in × 1.5-in (3.81-cm × 3.81-cm), 0.06-in (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
(2) Device mounted on FR4 material with 1-in^2 (6.45-cm^2), 2-oz (0.071-mm) thick Cu.



Max $R_{\theta JA}$ = 55°C/W when mounted on 1-in^2 (6.45-cm^2) of 2-oz (0.071-mm) thick Cu.



Max $R_{\theta JA}$ = 195°C/W when mounted on a minimum pad area of 2-oz (0.071-mm) thick Cu.

5.3 Typical MOSFET Characteristics

T_A = 25°C (unless otherwise stated)

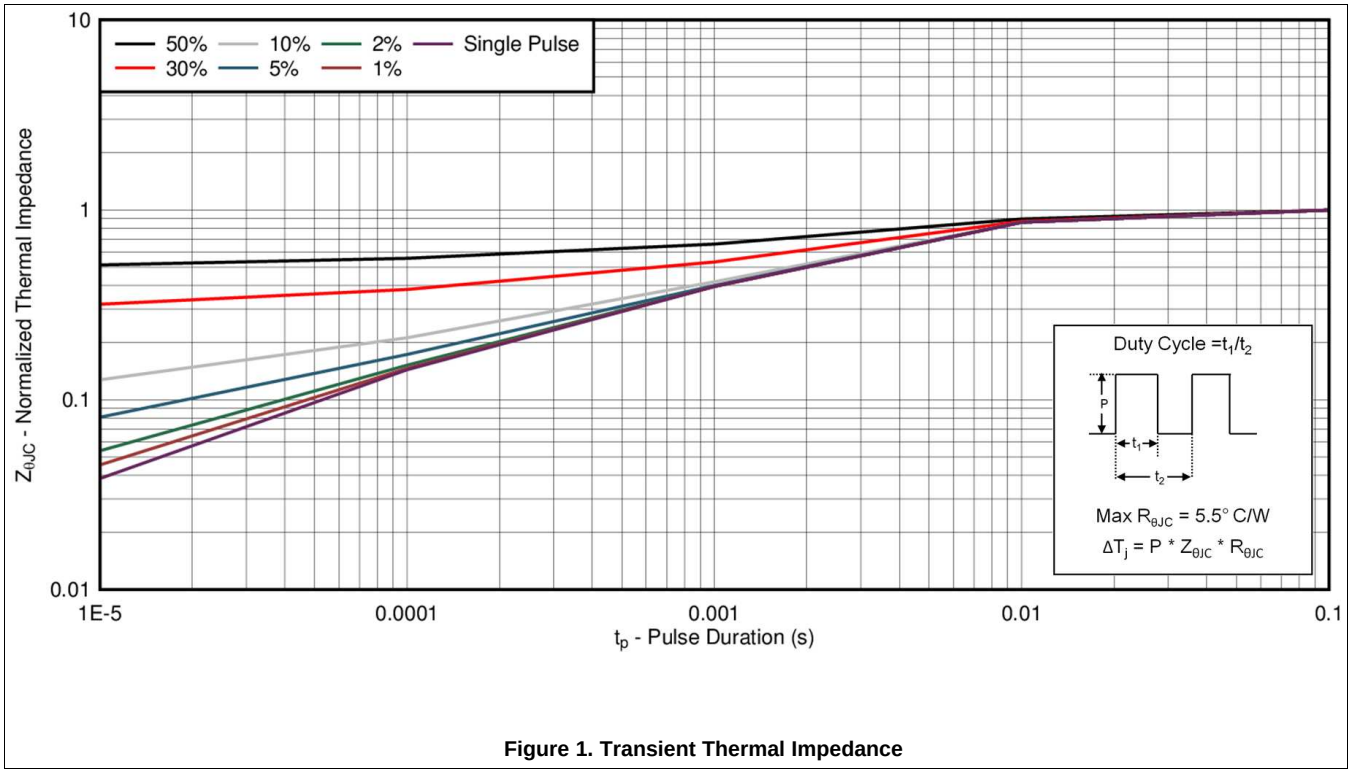


Figure 1. Transient Thermal Impedance

Typical MOSFET Characteristics (continued)

T_A = 25°C (unless otherwise stated)

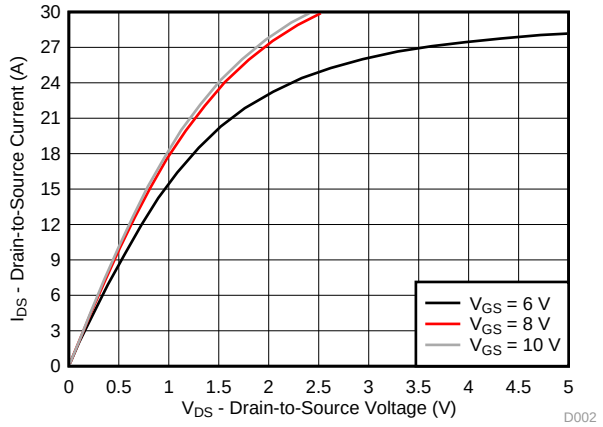


Figure 2. Saturation Characteristics

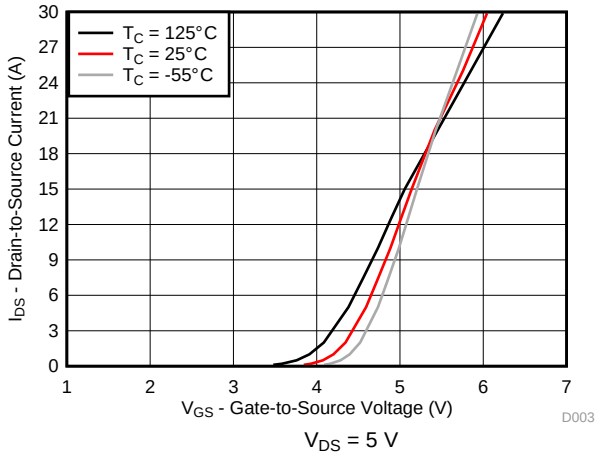


Figure 3. Transfer Characteristics

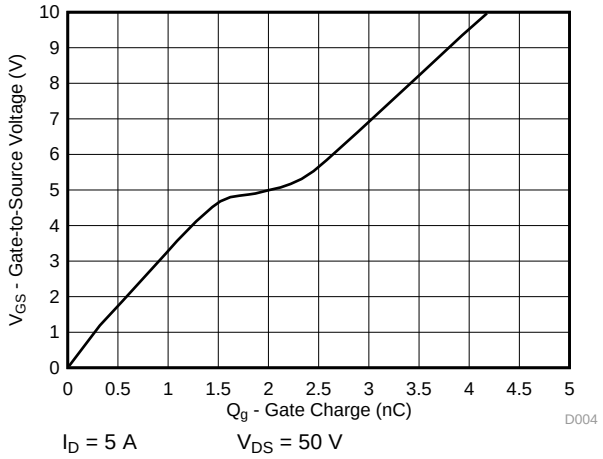


Figure 4. Gate Charge

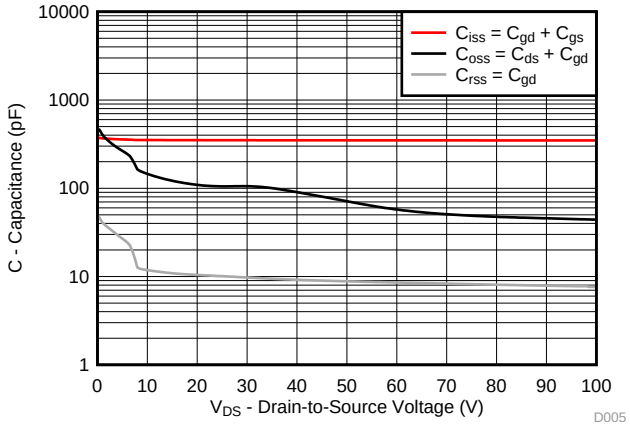


Figure 5. Capacitance

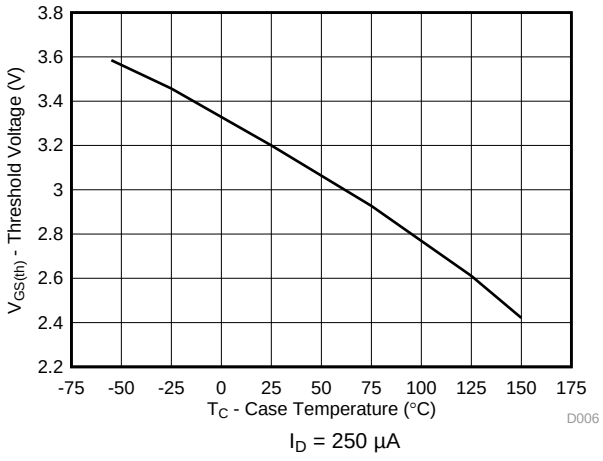


Figure 6. Threshold Voltage vs Temperature

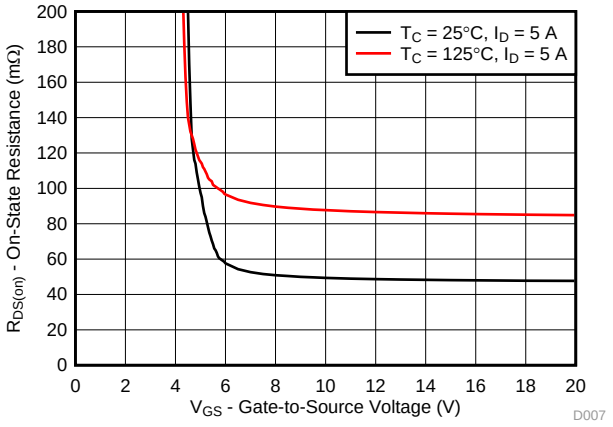


Figure 7. On-State Resistance vs Gate-to-Source Voltage

Typical MOSFET Characteristics (continued)

T_A = 25°C (unless otherwise stated)

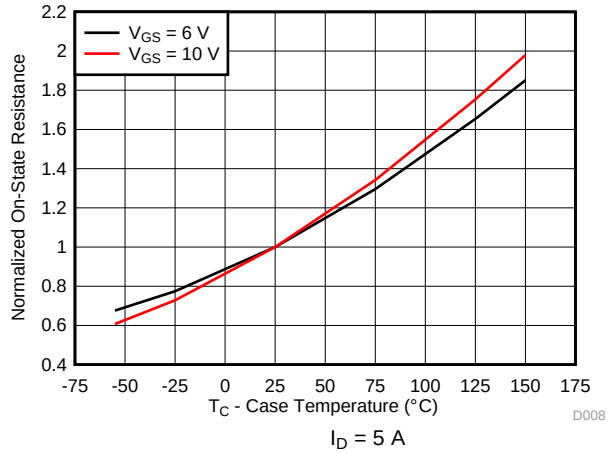


Figure 8. Normalized On-State Resistance vs Temperature

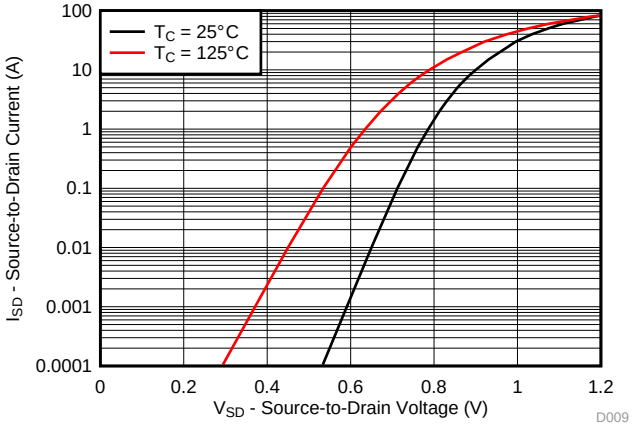


Figure 9. Typical Diode Forward Voltage

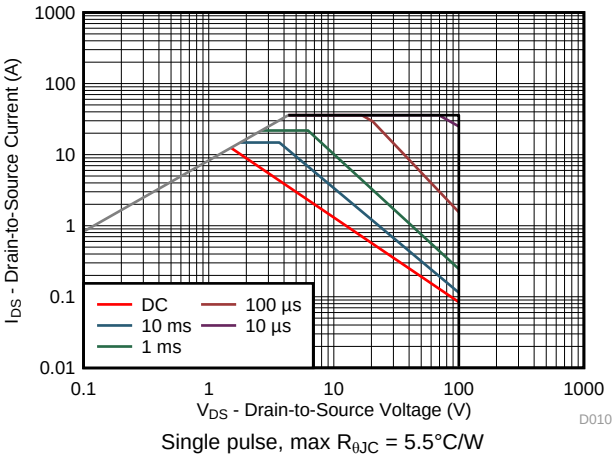


Figure 10. Maximum Safe Operating Area

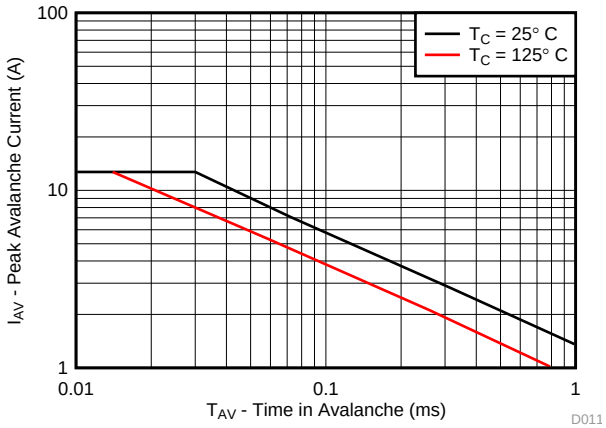


Figure 11. Single Pulse Unclamped Inductive Switching

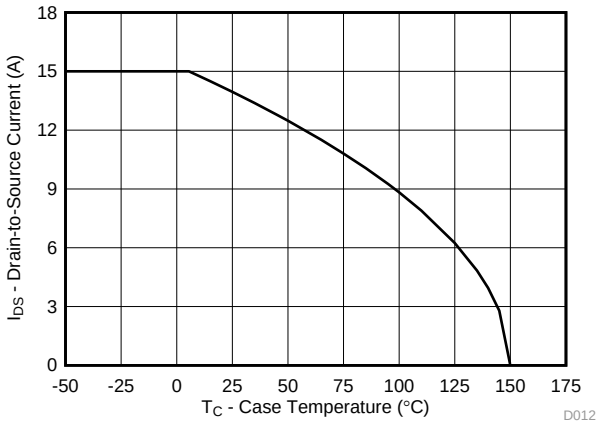


Figure 12. Maximum Drain Current vs Temperature

6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

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All other trademarks are the property of their respective owners.

6.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

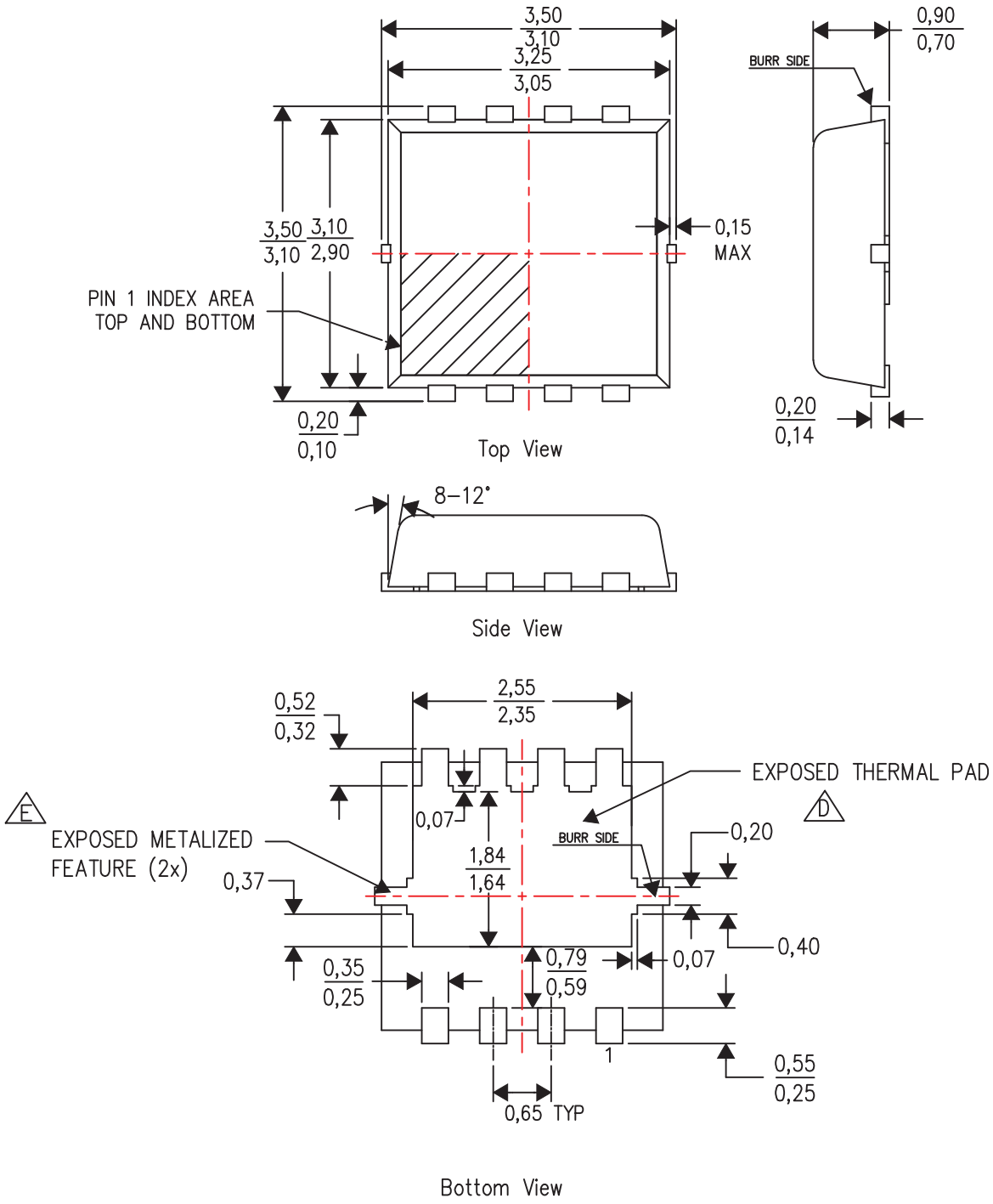
SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

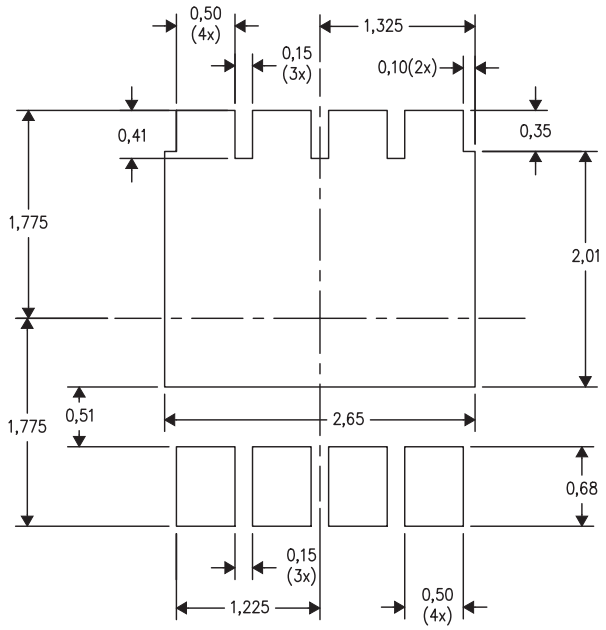
7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q3A Package Dimensions

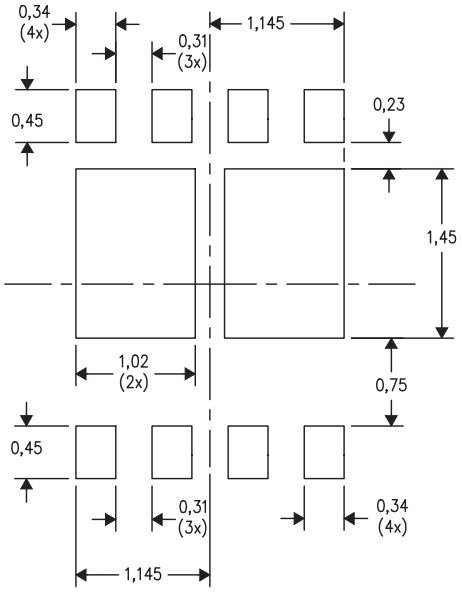


7.2 Q3A Recommended PCB Pattern

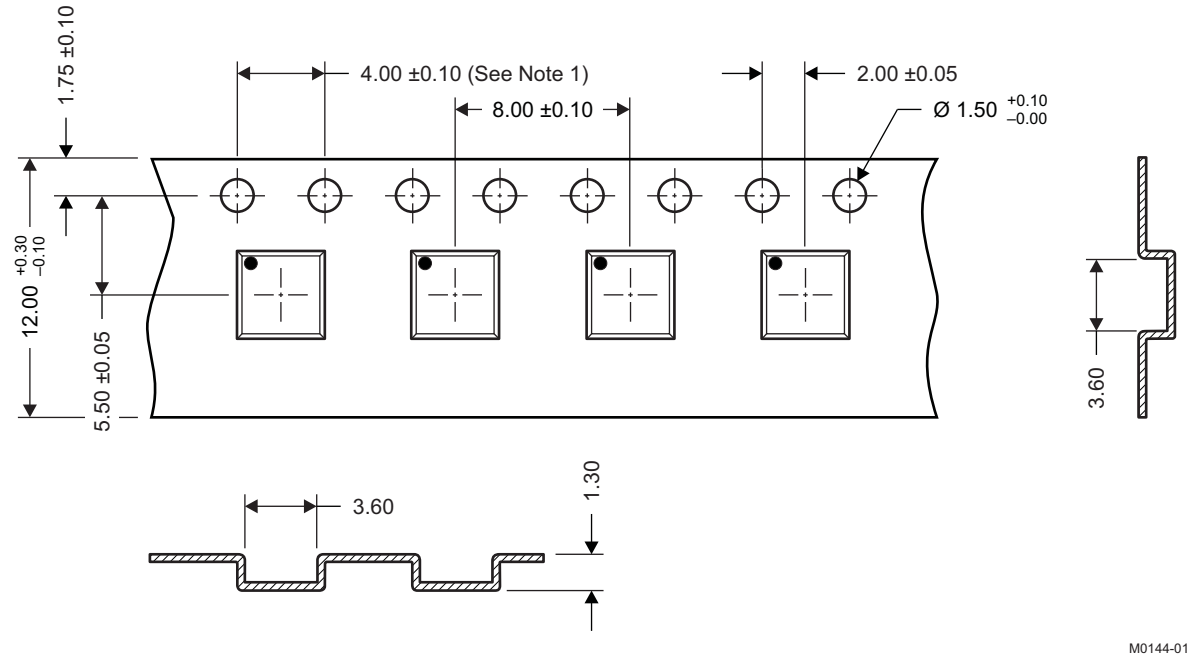


For recommended circuit layout for PCB designs, see *Reducing Ringing Through PCB Layout Techniques* (SLPA005).

7.3 Q3A Recommended Stencil Pattern



7.4 Q3A Tape and Reel Information



Notes:
1. 10-sprocket hole-pitch cumulative tolerance ±0.2.
2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm.
3. Material: black static-dissipative polystyrene.
4. All dimensions are in mm, unless otherwise specified.
5. Thickness: 0.3 ±0.05 mm.
6. MSL1 260°C (IR and convection) PbF-reflow compatible.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD19538Q3A	ACTIVE	VSONP	DNH	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 150	19538	Samples
CSD19538Q3AT	ACTIVE	VSONP	DNH	8	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 150	19538	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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